NSN 5962-01-163-9169

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-163-9169 **Body Length:** 0.925 inches **Body Width:** 0.310 inches **Body Height:** 0.185 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 1425-01-106-3089 guided missile **Features Provided:** Burn in and hermetically sealed and 3-state output and low power **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 16 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 8.3 volts power source **Memory Device Type:** Ram **Memory Capacity:** Unknown **Test Data Document:** 18876-13153469 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 18 printed circuit Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

Yes - demil/mli

Fiig:

A458a0